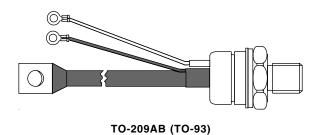


## Vishay High Power Products

# Phase Control Thyristors (Stud Version), 230 A



### **FEATURES**

- · Center amplifying gate
- International standard case TO-209AB (TO-93)



RoHS

- Hermetic metal case with ceramic insulator (Also available with glass-metal seal up to 1200 V)
- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- · Lead (Pb)-free
- Designed and qualified for industrial level

# PRODUCT SUMMARY I<sub>T(AV)</sub> 230 A

#### **TYPICAL APPLICATIONS**

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		230	Α		
I <sub>T(AV)</sub>	T <sub>C</sub>	85	°C		
I <sub>T(RMS)</sub>		360	А		
1	50 Hz	5700	۸		
I <sub>TSM</sub>	60 Hz	5970	A		
l <sup>2</sup> t	50 Hz	163	kA <sup>2</sup> s		
1-1	60 Hz	149	KA <sup>2</sup> S		
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 1600	V		
tq	Typical	100	μs		
T <sub>J</sub>		- 40 to 125	°C		

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE  VDRM/VRRM, MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V		V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} & I_{DRM}/I_{RRM} & \text{MAXIMUM} \\ & \text{AT T}_J = T_J & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$				
		500						
		800	900	30				
312303	12	1200	1300					
	16	1600	1700					

## **ST230SPbF Series**

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ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	-	190° condu	4000 and had been been been a		230	Α
at case temperature	$I_{T(AV)}$	160 Condu	180° conduction, half sine wave			°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 78 °C	case temperati	ure	360	
		t = 10 ms	No voltage		5700	
Maximum peak, one-cycle	ı	t = 8.3 ms	reapplied		5970	Α
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal half wave, initial $T_J = T_J$ maximum	4800	- -
		t = 8.3 ms	reapplied		5000	
		t = 10 ms	No voltage reapplied		163	- kA <sup>2</sup> s
Maximum 12+ for fusing	l <sup>2</sup> t	t = 8.3 ms			148	
Maximum I <sup>2</sup> t for fusing		t = 10 ms			115	
		t = 8.3 ms	reapplied		105	
Maximum I $^2\sqrt{t}$ for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		1630	kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.92	V	
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.98	ľ	
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.88	mΩ	
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$ 0.81		0.81	1115.2	
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 720 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.55	V	
Maximum holding current	I <sub>H</sub>	T. OF CO. and de complete ADV and all and		600	mA	
Maximum (typical) latching current	ΙL	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load			1000 (300)	IIIA

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs		
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1$ A/ $\mu$ s $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 \ ^{\circ}C$	1.0			
Typical turn-off time	t <sub>q</sub>	$I_{TM} = 300 \text{ A, } T_J = T_J \text{ maximum, dI/dt} = 20 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V 100 }\Omega, t_p = 500 \mu\text{s}$	100	μs		

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$	500	V/µs		
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	30	mA		



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TRIGGERING						
DADAMETER	SYMBOL	TEGT COMPLETIONS		VALUES		
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS		SI CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum, t	<sub>p</sub> ≤ 5 ms	10.0		w
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, f	= 50 Hz, d% = 50	2.0		vv
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum, t	<sub>p</sub> ≤ 5 ms	3.	.0	Α
Maximum peak positive gate voltage	+ V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms		20		V
Maximum peak negative gate voltage	- V <sub>GM</sub>			5.0		
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/current/voltage are the lowest value which will	180	-	
DC gate current required to trigger		T <sub>J</sub> = 25 °C		90	150	mA
		T <sub>J</sub> = 125 °C		40	-	
		T <sub>J</sub> = - 40 °C	trigger all units 12 V anode	2.9	-	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 125 °C		1.2	-	1
DC gate current not to trigger	I <sub>GD</sub>	T - T maximum	Maximum gate current/ voltage not to trigger is the maximum value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	10		mA
DC gate voltage not to trigger	$V_{GD}$	$T_J = T_J$ maximum		0.25		٧

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER SYMBOL		TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	T <sub>J</sub>		- 40 to 125	°C	
Maximum storage temperature range	T <sub>Stg</sub>		- 40 to 150		
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	0.10	K/W	
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>	Mounting surface, smooth, flat and greased	0.04		
Mounting torque, ± 10 %		Non-lubricated threads	31 (275)	N·m	
Mounting torque, ± 10 %		Lubricated threads	24.5 (210)	(lbf · in)	
Approximate weight			280	g	
Case style		See dimensions - link at the end of datasheet	TO-209AB (1	O-93)	

△R <sub>th</sub> JC CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.016	0.012					
120°	0.019	0.020					
90°	0.025	0.027	$T_J = T_J \text{ maximum}$	K/W			
60°	0.036	0.037					
30°	0.060	0.060					

Note

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• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

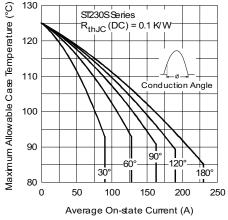


Fig. 1 - Current Ratings Characteristics

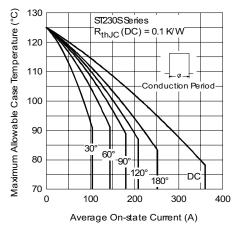


Fig. 2 - Current Ratings Characteristics

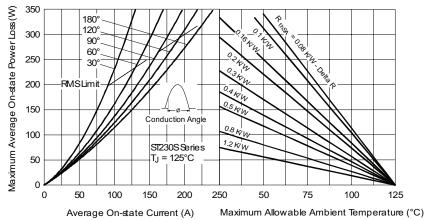


Fig. 3 - On-State Power Loss Characteristics

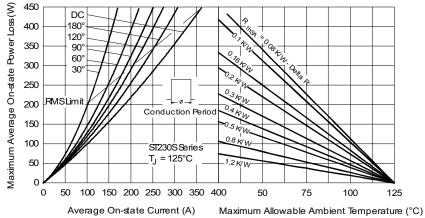


Fig. 4 - On-State Power Loss Characteristics



# Phase Control Thyristors (Stud Version), 230 A

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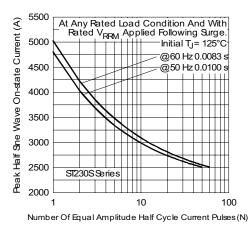


Fig. 5 - Maximum Non-Repetitive Surge Current

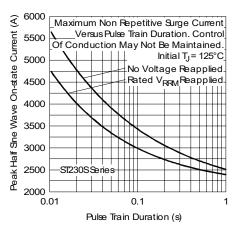


Fig. 6 - Maximum Non-Repetitive Surge Current

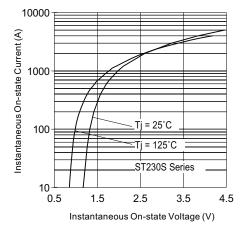


Fig. 7 - On-State Voltage Drop Characteristics

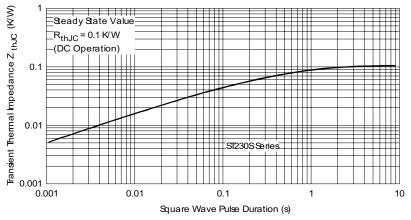


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

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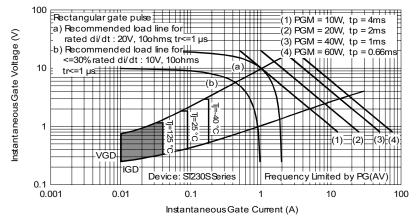
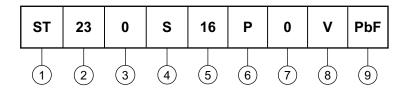


Fig. 9 - Gate Characteristics

#### ORDERING INFORMATION TABLE

**Device code** 



1 - Thyristor

2 - Essential part number

3 - 0 = Converter grade

4 - S = Compression bonding stud

5 - Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)

6 - P = Stud base 3/4"-16UNF2A threads

7 - 0 = Eyelet terminals (gate and auxiliary cathode leads)

1 = Fast-on terminals (gate and auxiliary cathode leads)

8 - • V = Glass-metal seal (only up to 1200 V)

• None = Ceramic housing (over 1200 V)

9 - Lead (Pb)-free

Note: For metric device M16 x 1.5 contact factory

LINKS TO RELATED DOCUMENTS		
Dimensions	http://www.vishay.com/doc?95077	

www.vishay.com

For technical questions, contact: ind-modules@vishay.com

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Vishay

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Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1